

# **Isc N-Channel MOSFET Transistor**

# **IPB027N10N3**

#### • FEATURES

- · With To-263(D2PAK) package
- · Low input capacitance and gate charge
- · Low gate input resistance
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



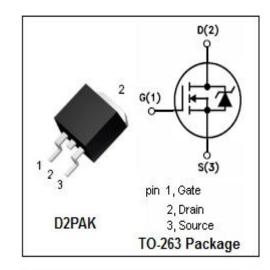
· Switching applications

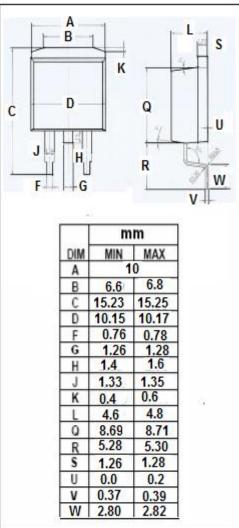


SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	100	V
V <sub>GSS</sub>	Gate-Source Voltage	±20	۸v
I <sub>D</sub>	Drain Current-ContinuousTc=25°C Tc=100°C	120	А
I <sub>DM</sub>	Drain Current-Single Pulsed	480	А
P <sub>D</sub>	Total Dissipation @T <sub>c</sub> =25℃	300	W
T <sub>ch</sub>	Max. Operating Junction Temperature	175	${\mathbb C}$
T <sub>stg</sub>	Storage Temperature	-55~175	${\mathbb C}$

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT		
Rth(ch-c)	Channel-to-case thermal resistance	0.5	°C/W		
Rth(ch-a)	Channel-to-ambient thermal resistance	40	°C/W		





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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 1mA	100			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =5V; I <sub>D</sub> =0.275mA	2.0		3.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =100A		2.3	2.7	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> = 0V			±0.1	μА
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =100V; V <sub>GS</sub> = 0V;Tj=25°C V <sub>DS</sub> =100V; V <sub>GS</sub> = 0V;Tj=125°C			1 100	μА
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =100A, V <sub>GS</sub> = 0 V		1.0	1.2	V

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